



S/N 10/053,300

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Vishnu K. Agarwal et al. Examiner: Hoai V Pham
Serial No.: 10/053,300 Group Art Unit: 2814
Filed: January 17, 2002 Docket No.: 303.780US1
Title: TRANSISTOR STRUCTURE HAVING REDUCED TRANSISTOR LEAKAGE ATTRIBUTES

AMENDMENT AND RESPONSE UNDER 37 CFR § 1.111

Mail Stop Amendment
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

This responds to the Office Action mailed on October 28, 2005. Please amend the above-identified patent application as follows.